

Dual 800mA,2V-6V Input,1.5MHz Synchronous Step-Down Converter

### **FEATURES**

- High Efficiency: Up to 96%
- 1.5MHz Constant Frequency Operation
- Dual 800mA Output Current
- No Schottky Diode Required
- 2V to 6V Input Voltage Range
- Output Voltage as Low as 0.6V
- PFM Mode for High Efficiency in Light Load
- 100% Duty Cycle in Dropout Operation
- Low Quiescent Current: 20μA
- Short Circuit Protection
- Thermal Fault Protection
- Inrush Current Limit and Soft Start
- $<1\mu$ A Shutdown Current
- DFN3X3-10 package

## **APPLICATIONS**

- Cellular and Smart Phones
- Wireless and DSL Modems
- PDAs
- Portable Instruments
- Digital Still and Video Cameras
- Set Top Box

#### **GENERAL DESCRIPTION**

The MT3428 is a 1.5MHz constant frequency current mode. dual high-efficiency step-down converter. It is ideal for portable equipment requiring very high current up to 800mA each channel from single-cell Lithium-ion batteries while still achieving over 90% efficiency during peak load conditions. The MT3428 also can run at 100% duty cycle for low dropout operation. extending battery life in portable systems while light load operation provides very low output ripple for noise sensitive applications. The MT3428 can supply up to 800mA output load current each channel from a 2V to 6V input voltage and the output voltage can be regulated as low as 0.6V. The high switching frequency minimizes the size of external components while keeping switching losses low. The internal slope compensation setting allows the device to operate with smaller inductor values to optimize size and provide efficient operation. The device is available in a Pb-free, 10-Lead DFN package and is rated over the -40°C to +85°C temperature range. This device offers two operation modes, PWM control and PFM Mode switching control, which allows a high efficiency over the wider range of the load.

# TYPICAL APPLICATION

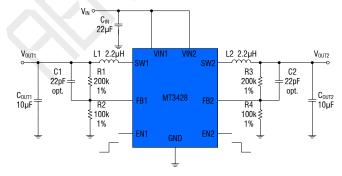


Figure 1. Basic Application Circuit

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# **ABSOLUTE MAXIMUM RATINGS** (Note 1)

VIN1,VIN2 Voltage0.3V to 6.5V EN1,EN2 Voltages0.3V to $(V_{IN} + 0.3V)$ FB1,FB2 Voltages0.3V to $(V_{IN} + 0.3V)$ SW1 Voltage0.3V to $(V_{IN} + 0.3V)$ SW2 Voltage0.3V to $(V_{IN} + 0.3V)$	Thermal Resistance $\theta_{JA}$
( )	
Power Dissipation0.6W	ESD HBM(Human Body Mode)2kV
Thermal Resistance θ <sub>JC</sub> 8°C/W	ESD MM(Machine Mode)200V

# PACKAGE/ORDER INFORMATION

TOP VIEW	Order Part Number	Package	Top Marking
1 10 SW 2 9 GN		DFN3X3-10	MT3428 <u>YMNNV</u> <u>FLLLLL</u>

# PIN DESCRIPTION

Pin Name	Pin Number	Description		
EN1 1		Chip Chanel 1 Enable Pin. Drive EN above 1.5V to turn on the part. Drive EN below		
		0.3V to turn it off. Do not leave EN floating.		
FB1	2	Chanel 1 Output Voltage Feedback Pin. An internal resistive divider divides the		
101	2	output voltage down for comparison to the internal reference voltage.		
VIN2	3	Chanel 2 Analog supply input pin.		
GND	4,9	Analog ground pin.		
SW2	5	Chanel 2 Power Switch Output. It is the switch node connection to Inductor. This		
3442		pin connects to the drains of the internal P-ch and N-ch MOSFET switches.		
EN2	6	Chip Chanel 2 Enable Pin. Drive EN above 1.5V to turn on the part. Drive EN below		
EINZ 0		0.3V to turn it off. Do not leave EN floating.		
FB2	7	Chanel 2 Output Voltage Feedback Pin. An internal resistive divider divides the		
FDZ I		output voltage down for comparison to the internal reference voltage.		
VIN1	8	Chanel 1 Analog supply input pin.		
SW1 10		Chanel 1 Power Switch Output. It is the switch node connection to Inductor. This		
		pin connects to the drains of the internal P-ch and N-ch MOSFET switches.		
EP	11	exposed pad, Must be connected to bare copper ground plane.		



# **ELECTRICAL CHARACTERISTICS (Note 3)**

(Chanel 1 Or Chanel 2, $V_{IN} = V_{FN} = 3.6V$ ,  $V_{OUT} = 1.8V$ ,  $T_A = 25$ °C, unless otherwise noted.)

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PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage Range		2		6	V
UVLO Threshold		1.7	1.9	2.1	V
Input DC Supply Current	(Note 4)				$\mu$ A
PWM Mode	$V_{OUT} = 90\%$ , $I_{LOAD} = 0$ mA		140	300	$\mu$ A
PFM Mode	$V_{OUT} = 105\%$ , $I_{LOAD} = 0$ mA		20	35	$\mu$ A
Shutdown Mode	$V_{EN} = 0V, V_{IN} = 4.2V$		0.1	1.0	$\mu$ A
Regulated Feedback	$T_A = 25^{\circ}C$	0.588	0.600	0.612	V
Voltage V <sub>FBX</sub>	$T_A = 0^{\circ}C \leq T_A \leq 85^{\circ}C$	0.586	0.600	0.613	V
Voltage V <sub>FBX</sub>	$T_A = -40^{\circ}C \leq T_A \leq 85^{\circ}C$	0.585	0.600	0.615	٧
Reference Voltage Line Regulation	V <sub>IN</sub> =2.7V to 5.5V		0.04	0.40	%/V
Output Voltage Accuracy	$V_{IN} = 2.7V \text{ to } 5.5V,$ $I_{OUT} = 10 \text{mA to } 800 \text{mA}$		0.04	0.40	% V <sub>out</sub>
Output Voltage Load Regulation	I <sub>OUT</sub> =10mA to 800mA		0.5		%/A
Oscillation Fraguency	$V_{OUT} = 100\%$		1.5		MHz
Oscillation Frequency	$V_{OUT} = 0V$		300		kHz
On Resistance of PMOS	$I_{sw} = 100 \text{mA}$		300	450	mΩ
On Resistance of NMOS	$I_{sw}$ =-100mA		300	450	mΩ
Peak Current Limit	$V_{IN} = 3V, V_{OUT} = 90\%$		1.5		Α
EN Threshold		0.30	1.0	1.50	٧
EN Leakage Current			±0.01	±1.0	μΑ
SW Leakage Current	$V_{EN} = 0V, V_{IN} = V_{SW} = 5V$		±0.01	±1.0	μΑ

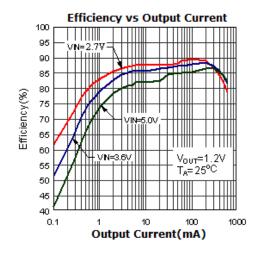
Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

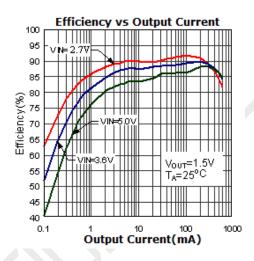
**Note 2:**  $T_J$  is calculated from the ambient temperature  $T_A$  and power dissipation  $P_D$  according to the following formula:  $T_J = T_A + (P_D) \times (38^{\circ}\text{C/W})$ .

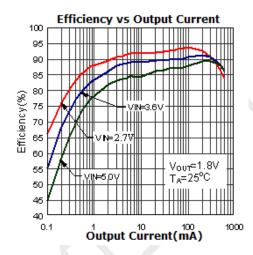
**Note 3:** 100% production test at  $+25^{\circ}$ C. Specifications over the temperature range are guaranteed by design and characterization.

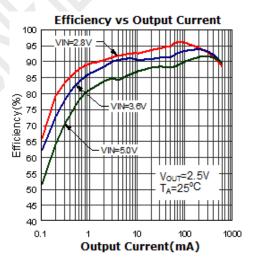
**Note 4:** Dynamic supply current is higher due to the gate charge being delivered at the switching frequency.

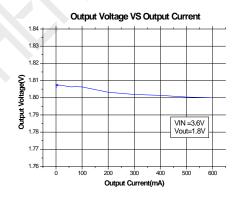
# TYPICAL PERFORMANCE CHARACTERISTICS

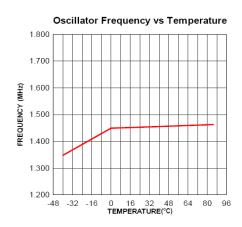


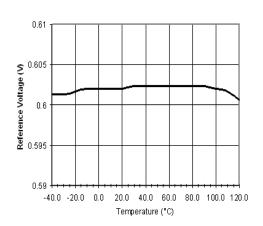


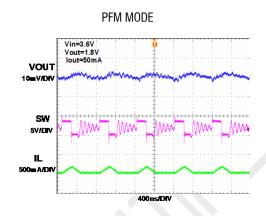


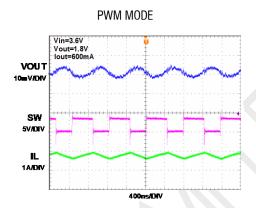














### **FUNCTIONAL BLOCK DIAGRAM**

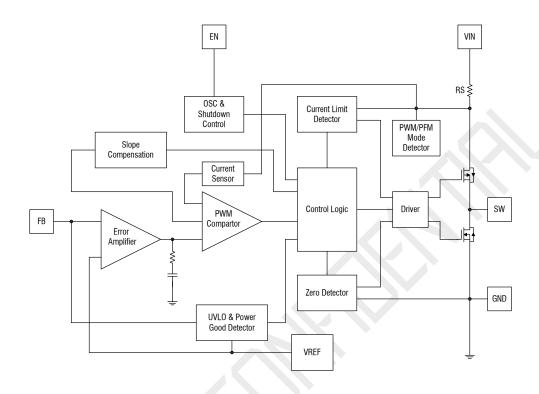


Figure 2. MT3428 Block Diagram

#### **FUNCTIONAL DESCRIPTION**

The MT3428 is a dual high output current monolithic switch mode step-down DC-DC converter. The device operates at a fixed 1.5MHz frequency, switching and uses a slope compensated current mode architecture. This step-down DC-DC converter can supply up to dual respective 800mA output current at  $V_{IN}$  = 3.6V and has an input voltage range from 2V to 6V. It minimizes external component size and optimizes efficiency at the heavy load range. The slope compensation allows the device to remain stable over a wider range of inductor values so that smaller values (1 $\mu$ H to 4.7 $\mu$ H) with lower DCR can be used to achieve higher efficiency. Only a small bypass input capacitor is required at the output. The adjustable output voltage can be programmed with external feedback to any voltage, ranging from 0.6V to near the input voltage. It uses internal MOSFETs to achieve high efficiency and can generate very low output voltages by using an internal reference of 0.6V. At dropout operation, the converter duty cycle increases to 100% and the output voltage tracks the input voltage minus the low R<sub>DS(ON)</sub> drop of the P-channel high-side MOSFET and the inductor DCR. The internal error amplifier and provides compensation excellent transient response, load and line regulation. Internal soft start eliminates any output voltage overshoot when the enable or the input voltage is applied.

# **AEROSEMI**

### **Setting the Output Voltage**

Figure 1 shows the basic application circuit for the MT3428. The MT3428 can be externally programmed. Resistors R1(or R3) and R2(or R4) in Figure 1 program the output to regulate at a voltage higher than 0.6V. To limit the bias current required for the external feedback resistor string while maintaining good noise immunity, the minimum suggested value for R2(or R4) is  $59k\Omega$  . Although a larger value will further reduce quiescent current, it will also increase the impedance of the feedback node, making it more sensitive to external noise and interference. Table 1 summarizes the resistor values for various output voltages with R2(or R4) set to either  $59k\Omega$  for good noise immunity or  $316k\Omega$  for reduced no load input current.

The external resistor sets the output voltage according to the following equation:

$$V_{\text{OUT}} = 0.6 \times \left(1 + \frac{\text{R1}}{\text{R2}}\right)$$

$$R1 = \left(\frac{V_{\text{OUT}}}{0.6} - 1\right) \times R2$$

Table 1 shows the resistor selection for different output voltage settings.

output voltage collinger					
V <sub>OUT</sub> (V)	R2=59kΩ	R2=316kΩ			
	R1(kΩ)	R1(kΩ )			
0.8	19.6	105			
0.9	29.4	158			
1.0	39.2	210			
1.1	49.9	261			
1.2	59.0	316			
1.3	68.1	365			
1.4	78.7	422			
1.5	88.7	475			
1.8	118	634			
1.85	124	655			
2.0	137	732			
2.5	187	1000			
3.3	267	1430			

Table 1: Resistor selections for different output voltage settings (standard 1% resistors substituted for calculated values).

### **APPLICATIONS INFORMATION**

#### **Inductor Selection**

For most designs, the MT3428 operates with inductors of  $1\mu H$  to  $4.7\mu H$ . Low inductance values are physically smaller but require faster switching, which results in some efficiency loss. The inductor value can be derived from the following equation:

$$L = \frac{V_{\text{OUT}} \times \left(V_{\text{IN}} - V_{\text{OUT}}\right)}{V_{\text{IN}} \times \Delta I_{\text{L}} \times f_{\text{OSC}}}$$

Where  $\Delta$  I<sub>L</sub> is inductor Ripple Current. Large value inductors result in lower ripple current and small value inductors result in high ripple current. For optimum voltage-positioning load transients, choose an inductor with DC series resistance in the  $50m\Omega$  to  $150m\Omega$  range.

PART NUMBER	VALUE (uH)	DCR (Ω MAX)	MAX DC CURRENT (A)	SIZE L*W*H(mm³)	
Sumida CDRH5D16	2.2	28.7	3	5.8x5.8x1.8	
	3.3	35.6	2.6	3.003.001.0	
	4.7	19	3.4	8.3x8.3x3.0	
Sumida CDRH5D16	2.2	23	3.3		
	3.3	29	2.6	5.2x5.2x3.0	
	4.7	39	2.1		

Table2.Recommend Surface Mount Inductors

#### **Input Capacitor Selection**

The input capacitor reduces the surge current drawn from the input and switching noise from the device. The input capacitor impedance at the switching frequency should be less than input source impedance to prevent high frequency switching current passing to the input. A low ESR input capacitor sized for maximum RMS current must be used. Ceramic capacitors with X5R or X7R dielectrics are highly recommended because of their low ESR and

small temperature coefficients. A  $22\mu$ F ceramic capacitor for most applications is sufficient. A large value may be used for improved input voltage filtering.

#### **Output Capacitor Selection**

The output capacitor is required to keep the output voltage ripple small and to ensure regulation loop stability. The output capacitor must have low impedance at the switching frequency. Ceramic capacitors with X5R or X7R dielectrics are recommended due to their low ESR and high ripple current ratings. The output ripple  $\triangle V_{\text{OUT}}$  is determined by:

$$\Delta V_{\text{OUT}} \leq \frac{V_{\text{OUT}} \times (V_{\text{IN}} - V_{\text{OUT}})}{V_{\text{IN}} \times f_{\text{OSC}} \times L} \times \left( \text{ESR} + \frac{1}{8 \times f_{\text{OSC}} \times C_{\text{OUT}}} \right)$$

A  $22\mu$ F ceramic can satisfy most applications.

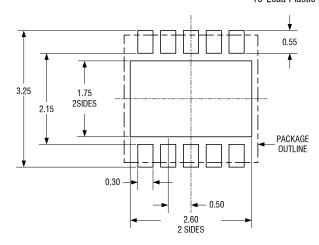
#### **PCB Lavout Recommendations**

When laying out the printed circuit board, the following checking should be used to ensure proper operation of the MT3428. Check the following in your layout:

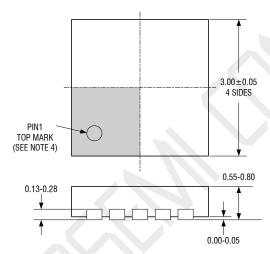
- The power traces, consisting of the GND trace, the SW trace and the VIN trace should be kept short, direct and wide
- Does the (+) plates of C<sub>IN</sub> connect to VIN as closely as possible. This capacitor provides the AC current to the internal power MOSFETs.
- Keep the switching node, SW, away from the sensitive V<sub>OUT</sub> node.
- $\blacktriangleright$  Keep the (-) plates of  $C_{IN}$  and  $C_{OUT}$  as close as possible.

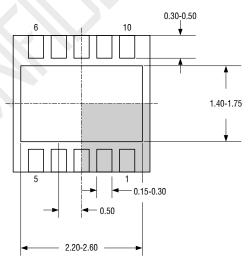
# **PACKAGE DESCRIPTION**

DFN3x3-10 Package 10-Lead Plastic DFN(3mm x 3mm)



#### RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS





BOTTOM VIEW-EXPOSED PAD

#### NOTE

- 1. ALL DIMENSIONS ARE IN MILLIMETERS
- 2. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
- 3. EXPOSED PAD SHALL BE SOLDER PLATED
- 4. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE

TOP AND BOTTOM OF PACKAGE



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